Tem perature dependent weak eld Hall resistance in 2D carrier system s

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U sing the D rude-Boltzm ann sem iclassical transport theory, we calculate the weak- eld H all resistance of a two-dimensional system at low densities and temperatures, assuming carrier scattering by screened random charged in purity centers. The temperature dependent 2D H all coe cient shows s striking non-m onotonicity in strongly screened systems, and in particular, we qualitatively explain the recent puzzling experimental observation of a decreasing H all resistance with increasing temperature in a dilute 2D hole system. We predict that the impurity scattering limited H all coe cient will eventually increase with temperature at higher temperatures. PACS Number: 71.30.+h; 73.40 Kp; 73.40 Qv

The behavior and the properties of the apparent two dimensional (2D) \metallic" phase continue to attract substantial attention [1] from experim entalists and theorists alike, even a decade after its original discovery [2]. In particular, the original observations on the strong m etallic (i.e. d = dT > 0) tem perature dependence of the 2D resistivity, (I), where the resistivity may increase by as much as a factor of 3 4 for a modest increase in tem perature (e.g. T = 100 m K3K) were followed by intriguing observations of large m agnetoresistance in an applied parallel magnetic eld. Phenom enologically the observed \metallicity", de ned as the maximum temperature induced enhancement of (I), exhibits strong system dependence, with 2D p-GaAs hole system being the most metallic and 2D n-G aAs electron system being the least m etallic with the 2D Si-based electron system s having intermediate metallicity. This system-dependent variation can be understood on the basis of our theoretical prediction [3] that the m etallicity arises from 2D screening properties, and is therefore controlled in the zeroth order theoretical prescription by the dimensionless parameters $q_{TF} = 2k_F$ and $T = T_F$, where q_{TF} , k_F , T_F are respectively 2D Thom as Ferm i screening wave vector, the Ferm i wave vector, and the Ferm i tem perature [4]. Since $q_{T\,F}$ =2k_F / m n $^{1=2}$ and T=T_F / m n 1 in 2D, the m etallicity increases with increasing (decreasing) carrier e ective mass m (carrier density n). This is why m etallicity is stronger at low er carrier densities and/or in higher e ective mass sem iconductor system s.

The idea [5] of the strongly temperature dependent screened charged in purity e ective disorder being the qualitative reason underlying the striking m etallic behavior of dilute 2D carrier system s has come to be known as the \screening theory" since the screening-induced regularization of the bare C oulom bic in purity disorder (in contrast to zero-range white noise disorder) intrinsic to sem iconductor system s is the crucial physical m echanism in this theory. The screening theory has been applied, with reasonable qualitative success, to explain the tem – perature and density [3,5,6] dependence as well the parallel m agnetic eld dependence [7] of the 2D \m etallic" resistivity [3,5]. M otivated by a puzzling recent experim ental observation [8], we develop in this Letter the rst theory, based on the screening model, for the tem perature dependence of the weak-eld H all resistance in dilute 2D carrier system s. Our theory is in excellent qualitative agreement with the experimental results [8] on the tem perature dependence of the weak eld H all resistance although quantitative discrepancies remain.

The recent Hall resistance measurements [8] take on particular signi cance since the experimental data reported by Gao et al. [8] disagree qualitatively with the so-called \interaction theory" [9,10], which has recently been much discussed and debated in the literature [9{15,3]. The interaction theory com plements the screening theory by carrying out a perturbative diagram matic calculation to include all (i.e. not just screening) interaction corrections to the 2D conductivity in the weak-disorder (the so-called \ballistic" regime), low tem perature limit de ned by (~ = $k_B = 1$) 0^{\perp} Т T_F , where 0 is the T = 0 transport (\D rude") relaxation time, 0 $(T = 0) = ne^2 = m$. The interaction theory, which purportedly improves and extends the screening theory by including higher-order interaction corrections, has several limitations: (1) the theory is restricted to only small tem perature induced corrections (T) to $_0$ $w \pm h (T) = 0 +$ (T), and j j $_0$ { as such this theory is, by construction, incapable of explaining the large tem perature-induced changes in the conductivity observed in the 2D \mbox{m} etallic" phase; (2) the theory is necessarily restricted to very low tem peratures T TF, which m ay not be achieved experim entally; (3) the theory has only been developed for 2D system swith white-noise bare in purity disorder, i.e. for an unrealistic model of zero-range bare in purity scattering potential (in reality, the impurities in 2D sem iconductor structures are random Coulombic charge centers, not zero-range neutral scatterers); (4) the interaction theory predicts only the leading-order tem perature dependence (\linear-in T") for 2D conductivity as $(T) = {}_{0}C_{1}(T=T_{F})$, where the tem perature-independent \cos cient C₁ is a universal (but unknown) function of density de ned by the Ferm i

liquid $\operatorname{triplet}$ " interaction parameter F_0 . Depending on the value of F_0 , (I) could be positive or negative. In spite of the fact that the only real prediction of the interaction theory for (T) is that the leading-order therm al correction to the 2D conductivity is linear in T (with an unknown positive or negative coe cient), and the experimental (T) is rarely linear over any appreciable tem perature range, there have been experim ental attem pts [12{15] to attribute the 2D m etallicity to interaction effects by thing the experimental (T) (T) 0, where $_0$ is obtained by a linear extrapolation to T = 0, to the form ula (T)= $_0 = C_1$ (T=T_F) and thereby obtain the tted coe cient C_1 and consequently extract the Ferm i liquid parameter F_0 . It may be appropriate here to m ention that the screening theory also predicts a leading-order linear temperature correction to (T). W hile both the screening theory and the interaction the- $T=T_{\rm F}$, the screening theory is not ory predict (T) lim ited to just the leading-order tem perature dependence and can be applied [3,5,6] to calculate the complete (T) { in fact, the screening theory becom es m ore accurate at higher tem peratures. The screening theory is, how ever, a self-consistent eld theory which only includes the e ects of screened e ective disorder arising from the charged in purity scattering leaving out all higher-order (i.e. beyond screening) e ects of interaction. Therefore, the applicability of the screening theory at very low -density strongly interacting 2D system is suspect and is only of qualitative validity. The importance of the interaction theory [9,10], in spite of its lim itations, arises from its very general and universal nature where the tem perature correction to the 2D conductivity is linked to universal functions of Ferm i liquid interaction param eters.

Since the temperature-dependent conductivity itself (at least, the leading-order tem perature correction) cannot distinguish between the interaction and the screening theory (with both predictions being = $_0$ / T=T_F), it becom es imperative to look for other more de nitive signatures for interaction e ects in low-density and lowtem perature 2D transport properties. This is where the tem perature dependence of weak-eld 2D Hall resistivity $_{\rm H}$ (T) takes on great signi cance as was emphasized in ref. [10], and recently, in ref. [8]. The interaction theory makes [10] very speci c (and falsi able) predictions about the connection between the (leading-order) tem perature corrections to 2D conductivity (T) and Hall resistivity $_{\rm H}$ (T) where $_{\rm H}$ (T) = $_{\rm H}^{0}$ + $_{\rm H}$ (T) with $_{\rm H}$ (T $\, ! \,$ 0). The predicted connection between (T) and $_{\rm H}$ (T), which has been discussed in detail with exem plary clarity in refs. [8] and [10], arises from the fact that in the interaction theory both of these tem perature corrections are controlled by the sam e Ferm i liquid param eters, and as such, a detailed and carefulm easurement of (T) at low temperatures necessarily completely determ ines the low-tem perature behavior of $_{\rm H}$ (T) in the same sample. Gao et al. carried out [8] such a comparison between $_{\rm H}$ (T) and (T) using the interaction theory [10] in an extrem ely high-quality 2D p-G aAs hole system which is metallic at extraordinary low densities down to 10^{10} cm² (where the 2D hole system should be very strongly interacting, making it a perfect system for testing the internal consistency of the interaction theory). The outcome as detailed in ref. [8] is a spectacular qualitative failure of the interaction theory: In the density range studied [8] by G ao et al. the Ferm i liquid param eters extracted from their experim ental (T) data should lead to, according to the interaction theory results of ref. [10], essentially a constant tem peratureindependent $_{\rm H}$ (T) except at the low est tem perature the interaction theory predicts a sm all (less than 1%) increase in $_{\rm H}$ (T) with increasing tem perature, whereas G ao et al. nd a smooth decrease (20%) in $_{\rm H}$ (T) with increasing temperature as T varies from 100 mK to 1K. Thus the interaction theory disagrees with the tem perature dependent H all resistance data of ref. [8], both qualitatively and quantitatively.

In this Letter we present the st calculated results for the 2D temperature dependent Hall resistance using the screening theory form alism. We solve the sem iclassical D rude-Boltzm ann transport equation [16] for the weakeld Hall resistance noting that the 2D Hall resistivity

 $_{\rm H}$ can be written as (c = 1)

$$_{\rm H} = \frac{\rm B}{\rm ne} r_{\rm H} ; \qquad (1)$$

where B is the applied weak magnetic eld and r_{H} , the so-called H all ratio [4], is given by

$$r_{\rm H} = h^2 i = h i^2;$$
 (2)

where is the (energy and temperature dependent) 2D carrier transport scattering time (the so-called momentum relaxation time) determ ined by the screened charged in purity scattering [3], and h i is the therm all average over the nite temperature Fermi distribution function { the detailed de nitions of and h i are given in the Appendix of ref. [3] and will not be repeated here. We note that h i determ ines the D rude-Boltzm ann conductivity through the relation (T) = $ne^{2}h$ i=m.

At T = 0, h²i h \hat{f} , giving $r_{H} = 1$ so that _H (T = 0) $_{H}^{0} = B$ =ne, the classical H all form u.a. At nite tem peratures it is well known that the H all ratio $r_{H} \notin 1$ due to therm alcorrections, and below we present our results for the calculated tem perature-dependent H all resistance in the D nude-B oltzm ann theory of screened charged im purity scattering. Following the standard notation we de ne the H all coe cient $R_{H} = d_{H} = dB = r_{H} = ne$.

O ur num erical results (shown below) for the tem perature dependent H all resistance are calculated assuming only carrier scattering by screened charged in purity scattering, leaving out phonon scattering (except in the inset of Fig. 2 (a)). For screening the C oulom bic disorder potential from the unintentional random charged in purities in the background and interfaces we use the random phase approximation (RPA) augmented by the Hubbard approximation (HA) for the local eld correction [17,18]. It is well-known that HA quantitatively improves upon the RPA, particularly at the very low carrier densities of interest [8], by including som e short-range exchangecorrelation e ects beyond the self-consistent eld approxin ation of RPA. Our calculations are done for the realistic G aA s/G a_{1 x} A l_xA s quantum well system s used in ref. 9 with the nite-width form -factore ects [3,4] associated with the quantum well con nem ent included in the theory. The charged in purities are assumed to be uniform ly random ly distributed in the background and interfaces, which set the overall resistivity scale (i.e. $_0^1$) in the system . All calculations are done for a quantum well width of 100A corresponding to the sam ple of ref. [8].

In Fig. 1 we show our calculated conductivity (T) and H all coe cient R_H (T) (inset) as a function of temperature for several hole densities. Both (T) and R_H (T), in agreement with the experimental data [B], decrease with increasing temperature, exhibiting some interesting nonmonotonicity that we discuss below. The overall decrease for (T), about a factor of 3 4, and for R_H (T), about 10 { 20%, are in excellent agreement with experiment although there are quantitative discrepancies in the details, which is to be expected given the highly approximate nature of our theory.

The most signi cant quantitative discrepancy between experiment and theory is that the overall temperature scale for the theory is som ew hat wider than that in the experiment [8]. While this problem can be somewhat recti ed by including additional scattering mechanisms (e.g. phonons, surface roughness, alloy disorder, rem ote impurities) which are invariably present in real 2D sem iconductor systems, our goal in this paper is to avoid excessive data tting (which would not be particularly m eaningful from the perspective of fundam ental understanding of the 2D m etallic phase) in order to establish a basic zeroth order qualitative understanding of the tem perature dependent 2D Halle ect. We therefore accept the quantitative discrepancy as the signature of the approxim ate nature of our theory, em phasizing the fact that the theory seems to be an excellent qualitative description of the experim ental observations in ref. [8].

In Fig. 2 we show our calculated H all ratio $r_{\rm H}$ (T) and the H all coe cient, $R_{\rm H}$ (T), as a function of tem perature. In particular, for $R_{\rm H}$ (T) we carry out a direct com parison between our screening theory and the experimental results from ref. [3] (cf. Fig. 2 (b) in ref. [3]). For the sake of comparison the interaction theory result [10] for $R_{\rm H}$ (T), adopted from Fig. 2 (b) of ref. [3], is also shown on the same plot. First, we note that while the interaction theory disagrees qualitatively and radically with the experimental results, our screening theory is in very good qualitative agreem ent. The screening theory catches well

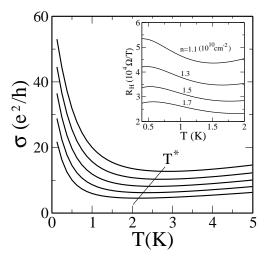


FIG.1. Calculated in purity scattering limited conductivity (T) as a function of temperature for di erent densities n = 1:1, 1.3. 1.5, 1.7, 1.9 $10^{10}\,\text{cm}^{-2}$ (bottom to top). T indicates the temperature at which d =dT changes sign. Inset shows the calculated Hall coe cient $R_{\rm H}$ (T) for di erent densities.

the overall m agnitude (20%) of the tem perature induced decrease in the Hall coe cient although there are quantitative discrepancies. The most important discrepancy is that the tem perature scale for the tem perature dependence is o by about 400 mK in the sense that the experim ental tem perature scale (the bottom abscissa in Fig. 2(b)) goes from 0 to 1.5K whereas our theoretical scale (the top abscissa of Fig. 2(b)) goes from 0.5K to 2.0K. This same discrepancy can be seen in Fig. 1 also where T , the temperature scale where d =dT changes sign at nite tem peratures (the so-called \quantum -classical crossover" [5] phenom enon), is consistently higher by roughly a factor 3 in the theory (com pare, for example, T in our Fig. 1(a) with the corresponding experimental T in Fig. 1 of ref. [8]). Currently, we have no good explanation for this discrepancy in the actual value of T it could, for example, be arising from an enhanced e ective mass (e.g. due to manybody electron-electron interaction) or due to the e ects of other scattering mechanisms such as remote impurities, which is known to suppress the theoretical T . For our qualitative theory of the tem perature dependent H all e ect we just accept this discrepancy in the tem perature scale and shift our theoretical results by 0.5 K in Fig. 2 (b), getting excellent qualitative agreem ent between experim ent [8] and the screening theory.

In discussing the overall temperature dependence of the Hall ratio r_H shown in Fig. 2 (a), where R_H $r_H = (ne)$, we see that there is a very striking non-monotonicity in r_H over the temperature scale 0 4K which has not been observed experimentally. But, the experimental results of ref. [3] clearly suggest tantalizing signs of possible non-monotonic behavior both at the low

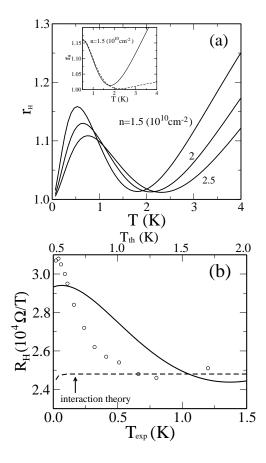


FIG. 2. (a) Calculated Hall ratio $r_{\rm H}$ (T) as a function of temperature for di erent densities by considering only screened charged in purities. The phonon contribution (dashed line) is given in the inset for $n = 1.5 \quad 10^{10} \, {\rm cm}^2$. (b) Calculated Hall coe cient with experimental data [8] and the result of the interaction theory for hole density $n = 1.65 \quad 10^{10} \, {\rm cm}^2$. The scale of $R_{\rm H}$ is set by experiment [8].

and the high tem perature ends with the data in ref. [8] unfortunately ending (both at low and high temperatures) precisely where the non-monotonicity may just be appearing. Since the tem perature scale of our screening theory is o by about 500 m K, the non-m onotonicity at the low temperature end (i.e. the initial rise of $r_{\rm H}$ with increasing T) is probably not observable because carrier heating is likely to prevent real low carrier tem peratures from being achieved. The higher tem perature rise of $r_{\rm H}$ (T), beyond T > 2K in Fig. 2(a), is a true prediction of our theory which should be experim entally tested, but this eventual increase of $r_{\rm H}$ (T) with T is likely to be m asked and considerably suppressed by phonon scattering e ects which become qualitatively important in lowdensity p-G aA s 2D hole system s of interest here already 1K (see the inset of Fig. 2(a)). Our prelim inary at T estim ate of phonon scattering e ects on the tem perature dependent Hall resistivity (the results shown in Figs. 1 and 2, we emphasize, include only carrier scattering by background screened charged in purities) suggests that

the maximum value of r_H is unlikely to exceed 1.1, and therefore the size of the non-monotonicity is suppressed as shown in the inset of Fig. 2(a).

Before concluding, we point out that, according to our screening theory, the decreasing R_{H} (T) with increasing tem perature observed in R ef. [8] and m an ifest in our F igs. 1 and 2 is obviously not an asym ptotic leading-order tem perature behavior, and as such, it is missed entirely in the interaction theory which predicts a qualitatively di erent behavior. We can calculate the analytic leading order tem perature dependence of the Hall ratio $r_{\rm H}$ (T) in the screening theory and nd it to be $r_{\rm H}$ (T) = 1 + $\frac{2}{3} \left(\frac{T}{T_{\rm F}}\right)^2$, н (Т) T^2 , in the strictly 2D lim it. This is difie. ferent from the leading-order prediction of the interaction theory, but this is understandable since the origin of the temperature correction in $R_{\rm H}$ is di erent in the two theories: in the screening theory it is a Ferm i surface averaging e ect at nite tem peratures whereas in the interaction theory, it is a true many-body Ferm i liquid renorm alization e ect. Our results, as com pared with experim ental data of ref. [8], dem onstrate that the asym ptotic leading-order theoretical tem perature dependence is not meaningful in understanding the temperature dependence of the 2D Hall coe cient | the tem perature dependence of R_H (T) arises from non-asym ptotic higherorder tem perature e ects and the asymptotic leadingorder tem perature dependence rem ains inaccessible experim entally because it happens at extrem ely low tem peratures. We have argued elsewhere [3] that the same m ay be true for the tem perature dependence of the 2D longitudinal resistivity also, which is rarely linear in the experim ental data.

We have developed the screening theory for the tem – perature dependent Halle ect in 2D \m etallic" system s. O ur results are in reasonable qualitative agreement with the recent experimental observations of G ao et al. [8]. We explain why the experimental data [8] disagree qualitatively with the interaction theory [10] by suggesting that the asymptotic leading-order temperature dependence of the interaction theory is simply inaccessible experimentally and is therefore physically uninteresting. We predict that the Hall coe cient, which decreases [8] with increasing temperature upto the highest measurement temperature (1.2K), will eventually increase by 5 10% when the temperature is increased to 2K or beyond, showing an interesting non-monotonic behavior.

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